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# Cavity structured S-NiO with improved energy density for aqueous asymmetric hybrid supercapacitors by CDA mechanism†

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Recently, hybrid supercapacitors have gained high recognition due to their improved energy density performance without affecting their power density. In this work, sulfur-doped nickel oxide (S-NiO) honeycomb nanostructure electrodes were prepared via a cost-effective chemical bath method through a Capping, Doping and Annealing (CDA) mechanism for Aqueous Asymmetric Hybrid Supercapacitors (AAHSc). The structural, elemental, morphological and electrochemical analysis of S-NiO as a positive electrode is explored in detail. After annealing, an amorphous to crystalline transformation of NiO was observed with a cubic structure owing to the honeycomb like morphology for optimum 1.42 atomic % sulfur doping. The CDA mechanism played a beneficial role in a synergistic process to prepare the S-NiO electrode with enhanced electrochemical properties for supercapacitor performance, exhibiting 71% capacitive current contribution. This optimized S-NiO electrode exhibited a remarkable specific capacitance ( $791.67 \text{ F g}^{-1}$  at a scan rate of  $20 \text{ mV s}^{-1}$ ) in 1 M KOH aqueous electrolyte. Graphite used as a negative electrode in the AAHSc device configuration (S-NiO//KOH//Graphite) showed a significant specific capacitance of  $77.69 \text{ F g}^{-1}$  at  $5 \text{ mA cm}^{-2}$  current density in a wide operating potential window of 1.8 V. The AAHSc device delivered a high energy density of  $34.96 \text{ W h kg}^{-1}$  at a power density performance of  $2567 \text{ W kg}^{-1}$  and  $19.36 \text{ W h kg}^{-1}$  even at a high-power density of  $7180 \text{ W kg}^{-1}$  for  $5 \text{ mA cm}^{-2}$ . More remarkably, 91% capacity retention with 81% coulombic efficiency was observed after 6,000 stability cycles at  $5 \text{ mA cm}^{-2}$ . The current work signifies the great potential of the S-NiO//KOH//graphite device in promoting and emphasising the development of a low-cost new approach towards hybrid energy storage materials.

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## 1. Introduction

The new era of energy storage devices requires portable, lightweight and cost-effective energy sources. Recently, much attention has been focused on developing hybrid supercapacitor devices with high energy-power density, long cycling life and safe operation to curtail energy crises.<sup>1–4</sup> It is essential to develop stable and highly efficient electrodes, such as 3D graphene, carbon nanotubes, carbon fibre, RuO<sub>2</sub>, polymers *etc.* However, the materials, as well synthesis methods and techniques, are very expensive.<sup>5</sup> Current issues with supercapacitors

restricting their practical application are relatively low capacitance due to limited active surface area and intrinsic supercapacitive behaviour of the electrode.<sup>6</sup> Coated multiple layers involve a polymer gel electrolyte with a different interface between the layer and coated configuration, which reduces the transport of ions by increasing the contact resistance and restricting the cathode to anode charge flow. This unwanted spacing can disintegrate various layers and reduces the effectiveness of the device.<sup>7</sup> Although supercapacitors are the most promising energy-storage devices with long cycle life and high-power supply, they are lacking in terms of high energy density.<sup>8–10</sup> Many researchers have attempted to make up for the lack of development of new electrode materials.<sup>11,12</sup> Herein, a successful attempt has been made to increase the energy and power density of the device at a wide operating potential window by a hybrid strategy through aqueous asymmetric supercapacitors. Additionally, aqueous electrolytes are inexpensive, non-toxic and safe to handle, having high ionic conductivity and mobility.<sup>13</sup>

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At present, numerous transition metal oxides are being investigated as electrode materials due to high theoretical specific capacitance as compared to conducting polymers and porous carbon materials.<sup>14,15</sup> In particular, the role of sulfur, with a lower electronegativity than oxygen, demonstrates narrow bandgap and high conductivity for transition metal sulfides.<sup>16,17</sup> The widely known transition metal oxides (TMOs: ZnO, RuO<sub>2</sub>, MnCo<sub>2</sub>O<sub>4</sub>, V<sub>2</sub>O<sub>5</sub>, Fe<sub>3</sub>O<sub>4</sub>),<sup>18–22</sup> transition metal hydroxides (TMHs: Mn(OH)<sub>2</sub>, Co(OH)<sub>2</sub>, Mo(OH)<sub>2</sub>, Ni(OH)<sub>2</sub>),<sup>23–27</sup> and transition metal sulfides (TMSSs: CuS, MoS<sub>2</sub>, NiS)<sup>28–30</sup> are potential materials for electrode design concerning electrochemical energy storage. High redox activities and reversibility make a pseudocapacitive material a promising electrode in supercapacitor design. Pseudocapacitive materials such as NiO have high theoretical capacitance (2584 F g<sup>-1</sup>), natural abundance, and high thermal stability, with excellent electrochemical properties.<sup>31</sup> Nanosheet based mesoporous NiO microspherical structures were synthesized by Lee *et al.*, having a specific capacitance of 403 F g<sup>-1</sup> after 1000 charge discharge cycles.<sup>32</sup> Yu *et al.* synthesized hollow sphere nanosheet NiO, exhibiting capacitance of 600 F g<sup>-1</sup> after 1000 cycles at 10 A g<sup>-1</sup>.<sup>33</sup> Yuan *et al.* showed that NiO nano/micro superstructures deliver a specific capacitance of 710 F g<sup>-1</sup> at 1 A g<sup>-1</sup> and with retention of 98% after 2000 cycles.<sup>34</sup> However, the development of NiO structures for high electrochemical performance supercapacitor electrodes is extremely tricky. Paravannoor *et al.* prepared NiO nanowires by a hydrothermal route and observed a specific capacitance of 750 F g<sup>-1</sup> with 88% retention after 1000 cycles.<sup>35</sup> On the other hand, efforts are being made to increase the electrochemical performance of electrodes *via* composites, doping, and the involvement of conductive additives (like active materials with porous current collectors)<sup>36,37</sup> using many methods such as hydrothermal electrodeposition, chemical bath deposition, etc, in which current collectors provide abundant electro active sites to assist rapid faradaic redox reactions.<sup>38–40</sup> NiO nanoflake arrays synthesised by Yan *et al.* using the hydrothermal technique showed specific capacitance of 400 F g<sup>-1</sup> at 2 A g<sup>-1</sup>, and capacitance retention of 428 F g<sup>-1</sup> was observed after 5000 cycles.<sup>41</sup> Wu *et al.* synthesised NiO-attached graphene oxide owing specific capacitance of 569 F g<sup>-1</sup> at 1 A g<sup>-1</sup> with ~80% capacitance retention after 3000 charge discharge cycles.<sup>42</sup> Zhao *et al.* used graphene oxide (GO) directly to fabricate a composite material with 2D graphene/NiO, showing a specific capacitance of 525 F g<sup>-1</sup> at a current density of 200 mA cm<sup>-1</sup>, and capacity retention of 95.4% can be maintained after 1000 cycles.<sup>43</sup> Ji *et al.* synthesised polypyrrole encapsulated flower-like NiO by a hydrothermal route, which exhibited a specific capacitance of 595 F g<sup>-1</sup> at 1 A g<sup>-1</sup> and 80.7% capacitance retention for 1000 cycles.<sup>44</sup> Meanwhile, the synthesis of S doped NiO as active materials can effectively improve material properties. Guai *et al.* demonstrated sulfur doped NiO thin film as an alternative to Pt for dye-sensitized solar cells (DSSC) applications.<sup>45</sup> Therefore, sulfur doping may considerably alter the electrochemical characteristics of NiO towards a reliable positive electrode material for supercapacitors. An ultrathin sulfur-doped NiO spherical nanosheet electrode was

synthesized by Singu *et al.* with acetylene black and a polyvinylidene fluoride (PVDF) binder for redox supercapacitors using SDS as an anionic surfactant and structure-directing agent. They reported a capacitance of 313 F g<sup>-1</sup> at a scan rate of 5 mV s<sup>-1</sup> in 1 M KOH with almost 99% capacity retention after 1000 charge–discharge cycles.<sup>46</sup>

In this work, the aim is to achieve a high potential charge storage device with a hybrid approach cost effectively *via* a simple chemical bath method. Herein, S-NiO deposition is controlled through a Capping, Doping and Annealing (CDA) mechanism on stainless steel substrates for optimum electrochemical execution. The amount of ammonia solution (capping agent) in the bath is varied, and 10, 20 and 30 mL are used for the as-synthesized samples (without annealing) S1, S2 and S3, and annealed samples A1, A2 and A3, respectively. In this study, the A1 electrode achieved superior electrochemical performance compared to the other electrodes with a specific capacitance of 791.67 F g<sup>-1</sup> at a 20 mV s<sup>-1</sup> scan rate and 766 F g<sup>-1</sup> for a current density of 0.8 mA cm<sup>-2</sup> in aqueous 1 M KOH. Furthermore, an aqueous asymmetric hybrid supercapacitor (AAHSc) device configured using A1 as a positive electrode and graphite as a negative electrode in the S-NiO//KOH//graphite form is a potential candidate for energy storage. Thus, we report a hybrid approach of surface development through CDA to realize a synergetic effect and superior high-energy electrochemical performance of S-NiO//KOH//graphite through a wide potential.

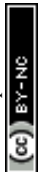
## 2. Experimental

### 2.1 Materials and method

The S-doped nickel oxide nanostructure was prepared using low-cost chemical bath deposition (CBD) *via* homogenous precipitation. Nickel sulphate (hexahydrate) extra pure [NiSO<sub>4</sub>·6H<sub>2</sub>O] and thiourea 99% AR [CH<sub>4</sub>N<sub>2</sub>S], were used as precursor sources of nickel and sulfur. Ammonia solution 30% AR/ACS [NH<sub>4</sub>OH] was used as the capping agent for cation complexation. All the chemicals were of analytical grade obtained from Loba Chemie Ltd without any further purification. A stainless-steel (SS) substrate (4 × 1 cm<sup>2</sup>, 304 grade) was used as the conducting substrate for deposition. Substrate cleaning was carried out by polishing with zero grade polish paper and rinsing thoroughly with double distilled water.

### 2.2 Formation of S-NiO/SS electrode and reaction mechanism

The synthesis processes of the S-NiO/SS electrode are schematically illustrated in Fig. 1., and include mainly three steps. First, 0.1 M NiSO<sub>4</sub>·6H<sub>2</sub>O solution is prepared for a 25 mL bath using double distilled water (DDW). In the capping step, the amounts of liquor ammonia (NH<sub>4</sub>OH) added to the Ni precursor solution are 10 mL, 20 mL, and 30 mL, resulting in strong complexation of Ni ions for controlled release through reaction kinetics. Through van der Waals forces, amine capped metal ions easily get adsorbed on the heterogeneous surface of the



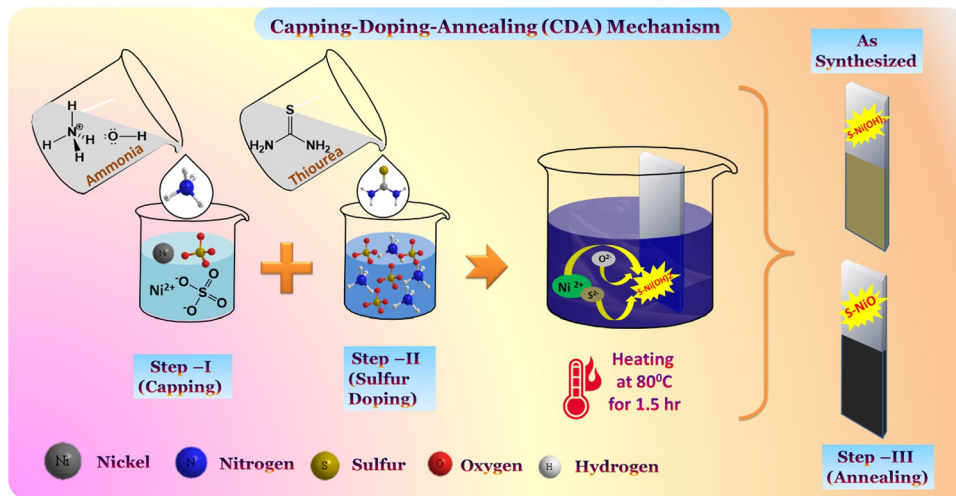
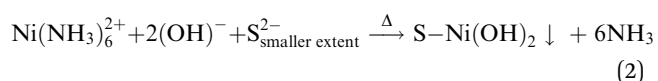


Fig. 1 Schematic illustration of the deposition of nanostructured honeycomb S-NiO on an SS substrate through the three-step CDA mechanism by successful CBD method.

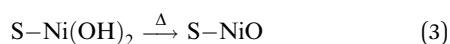
substrate, represented by following reaction



Second, in the sulfur doping step, another bath of 0.1 M thiourea ( $\text{CH}_4\text{N}_2\text{S}$ ) solution as a source of sulfur is prepared in 25 mL DDW, and both the solutions are mixed thoroughly by constant stirring on a hot plate. Thiourea as an organic sulfur source has diverse advantages of flexibility and structure-shape diversity to control the nucleation and growth. The bath temperature ( $80^\circ\text{C}$ ) supplies energy to break the complex and release Ni ions for reaction in a basic bath with a smaller extent of sulfur dissociation from thiourea. Thus,  $\text{S}^{2-}$  can be released controllably from the organic sulfur source, supplying favourable conditions for the nucleation-growth and accordingly, the structural and morphological modification occurs. Furthermore, well cleaned conducting SS substrates are immersed in the reaction bath for deposition. A heterogeneous reaction occurred during the precipitation and dark greyish deposition takes place on the substrate surface shown by the following reaction:



The deposited films on the SS were repeatedly washed with DDW. Finally, in the annealing step, as-synthesized samples are subjected to post heat treatment at  $300^\circ\text{C}$  for 3 hr to remove hydrous content, and dark brownish S-NiO/SS electrodes are obtained, as shown by the following reaction:



The quantity of ammonia (*i.e.* the degree of complexation) in the bath was varied, and 10 mL, 20 mL & 30 mL were assigned to as-synthesized  $\text{S}_1$ ,  $\text{S}_2$  &  $\text{S}_3$ , and annealed S-NiO/SS  $\text{A}_1$ ,  $\text{A}_2$  &  $\text{A}_3$  sample electrodes, respectively.

### 2.3. Characterization techniques

The structures of the samples were characterized by X-ray diffraction (XRD) on a Rigaku Ultima diffractometer using Cu-K $\alpha$  radiation ( $\lambda = 1.54 \text{ \AA}$ ). The morphology was characterized by field emission scanning electron microscopy (FE-SEM, Mira-3, Tescan Pvt. Brno-Czech Republic). Energy dispersive analysis (EDS) measurements were carried out on an Oxford Instrumentations system, inbuilt with FE-SEM. The chemical structure and various oxidation states of S-NiO were examined by an X-ray photoelectron spectroscopy (XPS, PHI 5000 Versaprobe II) system.

All electrochemical measurements were performed by a ZIVE MP1 electrochemical workstation. The supercapacitive performance was analyzed by forming a three-electrode electrochemical cell setup with a platinum plate as a counter electrode, an S-NiO electrode as a working electrode and a saturated calomel electrode (SCE) as a reference electrode. Electrochemical studies were carried out by using cyclic voltammetry (CV), galvanostatic charge discharge (GCD) and electrochemical impedance spectroscopy (EIS) tests in 1 M KOH aqueous electrolyte.

## 3. Results and discussion

### 3.1 Structural analysis

To undertake a crystallographic study of the thin films, XRD measurements were recorded in the range of  $10^\circ$ – $80^\circ$ . All as-synthesized samples exhibited amorphous nature as shown in Fig. S1 (ESI $^\dagger$ ). From Fig. 2(a) it is clearly observed that for the annealed samples, remarkable diffraction peaks in the XRD patterns at  $2\theta^\circ$  of  $\sim 37.26^\circ$ ,  $43.75^\circ$ ,  $62.81^\circ$ , and  $79.31^\circ$  indicate successful NiO formation with (1 1 1), (2 0 0), (2 2 0) and (2 2 2) planes, respectively. These diffraction peaks are in good agreement with the JCPDS card no. 47-1049,  $Fm\bar{3}m$  (225),  $a = 4.1771 \text{ nm}$ .

Some intense diffraction peaks observed at  $2\theta$  of  $44.58^\circ$ ,  $51.38^\circ$  and  $75.30^\circ$  are ascribed to the SS substate and indicated



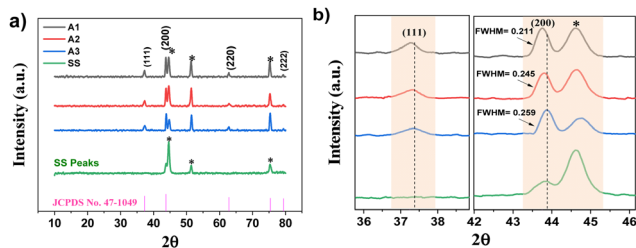


Fig. 2 X-Ray diffraction patterns of (a) S-NiO thin films, and (b) magnified portion highlighting the peak shift.

by asterisks (\*). The results clearly showed that the impurity peaks were absent, and there was a small extent of sulfur substitution in the NiO lattice sites in the annealed samples. It is clearly confirmed that the annealing process reformed as synthesised amorphous samples into samples with good crystallinity. It is noticed in Fig. 2(b) that there is a decrease in sulfur content with an increase in capping, *i.e.* degree of complexation. The peak broadenings, *i.e.* FWHM values, are noticeably found to increase, which indicates crystallite size reduction from A<sub>1</sub> to A<sub>3</sub>. Also, there is marginal peak shifting towards smaller angles, thereby confirming the effect of S-doping from XRD analysis. Chang *et al.* and Li *et al.* found the same effect of sulfur doping, resulting in XRD peak shifting at smaller angles, in good agreement with our results.<sup>47,48</sup> The average crystallite size of the sample decreases from A<sub>1</sub> to A<sub>3</sub> with a higher degree of ammonia complexation and decrease in sulfur content given by Debye-Scherrer's equation. Similar results were obtained by Yang *et al.* and Diallo *et al.*<sup>49,50</sup> Crystallite size, dislocation density, microstrain, band gap values, *etc.* for A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> are summarized in Table ST1 (ESI<sup>†</sup>).

The energy storage capacity of materials has been influenced by the deformation mechanism and dislocation.<sup>51</sup> The A<sub>1</sub> electrode exhibited the lowest dislocation density and micro-strain compared to A<sub>2</sub> and A<sub>3</sub>, which is a sign of good energy storage capacity. With a high degree of capping, the doping of sulfur decreases and results in a reduction in the crystallite size with an increase in the dislocation density, micro-strain, and inter-planar spacing.<sup>52</sup> A<sub>1</sub> has excess sulfur as compared to the A<sub>2</sub> and A<sub>3</sub> electrodes, which is why the dislocation reduces. Similar observations have been previously reported concerning the reduction of dislocation due to sulfur doping.<sup>53,54</sup>

### 3.2 Morphological and elemental analysis (FESEM and EDS)

Investigation of surface morphology and elemental analysis for as-synthesised and annealed thin samples were carried by FESEM and EDS. The morphologies of the as-synthesised amorphous samples (S1, S2 and S3) revealed undistinguished fuzzy nanoflake like morphology with a lower thickness, as shown in Fig. S2 (ESI<sup>†</sup>). However, the annealed crystalline electrodes in Fig. 3(a1) and (a2) show the morphology of the A<sub>1</sub> sample featuring cavity surfaces looking like a honeycomb structure. A high degree of complexation resulted in the distribution of fewer Ni ions and resulted in the deviation of the morphology from a honeycomb like to a flake like

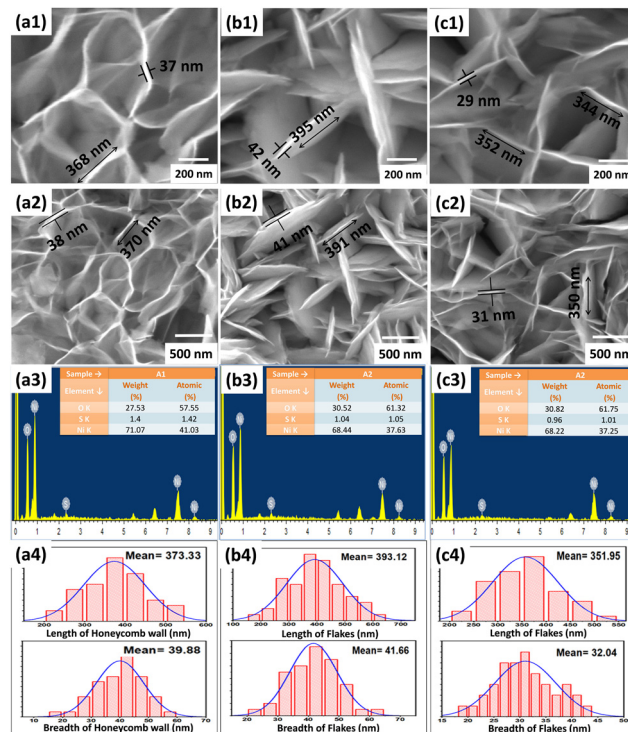


Fig. 3 FESEM morphologies, EDS spectra and histogram measurements for samples A<sub>1</sub> ((a1)–(a4)), A<sub>2</sub> ((b1)–(b4)) and A<sub>3</sub> ((c1)–(c4)).

nanostructure, with a change in dimensions, as shown in Fig. 3(b1), (b2) and (c1), (c2). The insets of Fig. 3(a3), (b3) and (c3) clearly show the elemental analysis (% of Ni, O and S) of the S-NiO A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> samples. It is observed that the nickel and sulfur content along with oxygen vacancies decrease with a greater degree of capping. Table ST2 (ESI<sup>†</sup>) shows the at% of elements for all samples. Sample A<sub>1</sub> is Ni rich (41.03 at%) with high sulfur (1.42 at%) and more oxygen vacancies, *i.e.* lower oxygen content (57.55 at%) than the A<sub>2</sub> and A<sub>3</sub> samples. A high capping bath releases less Ni during the reaction due to heavy complexation affecting the growth kinetics and *vice versa*.

Fig. 3(a4), (b4) and (c4) show histograms for the average length and breadth of nanostructured samples A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub>, respectively. For A<sub>1</sub> the honeycomb wall has average length and breadth of  $373.33 \pm 9.34$  nm and  $39.88 \pm 6.61$  nm. The annealing process is popular to modify morphology, enhancing crystallinity and other structural properties.<sup>55,56</sup> The effect of annealing on the growth morphology for the S<sub>1</sub> electrode, from a fuzzy to a sturdy honeycomb like structure (with more active sites and large surface area of cavities) is schematically shown in Fig. S3 (ESI<sup>†</sup>). Sharma *et al.* developed NiO thin films and observed that annealing resulted in increased crystallinity and affected surface morphology.<sup>57</sup> Such a honeycomb like morphology has multiple active sites to increase the specific capacitance.<sup>58</sup> Also, ammonia is important to achieve superficial morphology. Deng *et al.* observed precipitation that means morphology is controlled by the ammonia concentration.<sup>59</sup> A facile ammonia influence has been used to grow nanoporous NiO films with a well-defined unique porous



structure.<sup>60</sup> Also, crystallinity and particle size of NiO improved when using ammonia capping.<sup>61</sup> Furthermore, a flower-like structure is credited to ammonia decomplexation.<sup>62</sup>

Fig. 3(b1)–(b4) showing the A<sub>2</sub> electrode, demonstrate a nano-flake structure. The drastic morphology change of the honeycomb like structure into nano-flakes is due to higher complexation and lower sulfur (1.05 at%) doping. Fig. 3(b4) shows the average length and breadth of the nano-flakes to be 393.12 ± 11.07 nm and 41.66 ± 5.95 nm, as evaluated from the histogram for the A<sub>2</sub> electrode. Fig. 3(c1)–(c4) reveal that the A<sub>3</sub> electrode with the same nano-flake structure exhibits smaller length-breadth and thickness with sizes of 351.95 ± 8.21 nm and 32.04 ± 4.66 nm. A higher degree of capping resulted in a small decrease in sulfur (1.01 at%) content for A<sub>3</sub>. Furthermore, the at% values of Ni corresponding to the A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> electrodes are 41.03, 37.63 and 37.25%, respectively. This conclusively indicated that the A<sub>1</sub> electrode has the highest wt% and at% of the Ni sites, which are actively involved in the redox mechanism, along with sulfur content, compared to the other samples as shown in Table S2 (ESI<sup>†</sup>).

### 3.3 X-Ray photoelectron spectroscopy (XPS)

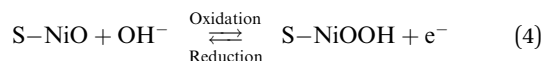
The valence information and surface chemical composition of constituent elements in the synthesized S-NiO were examined by X-ray photoelectron spectroscopy (XPS). The broad survey spectrum and high-resolution XPS spectra of Ni 2p, O 1s and S 2p levels are shown in Fig. 4. The wide survey scan spectrum (Fig. 4a) again suggests the presence of Ni, O and S elements, which is consistent with the above EDS result.

The high-resolution spectra of the Ni 2p states as revealed by Fig. 4(b) show two prominent peaks with binding energies of 855.6 eV and 873.4 eV, indicating two spin-orbit doublets of Ni 2p<sub>3/2</sub> and Ni 2p<sub>1/2</sub>.<sup>63</sup> The difference between these two energy bands is around 17.8 eV, strongly confirming the presence of

divalent nickel ions. The O1s states of S-NiO are shown in Fig. 4(c). The O1s spectrum is deconvoluted into two peaks. The first peak was located at 531.3 eV representing the O1s spectra of the metal oxygen bond (M–O) *i.e.* NiO, and the second peak was located at 532.5 eV, indicating the surface hydroxyls/C–O bond.<sup>64</sup> The sulfur core spectrum level of S-NiO is shown in Fig. 4(d). The sulfur S 2p peak was located at 168.9 eV. A similar result was reported by Singu *et al.*<sup>46</sup> The prominent peak over 168 corresponds to the S–O bond.<sup>65</sup> These XPS results collectively support the successful formation of S doped NiO nanosheets.

### 3.4 Electrochemical properties

CDA influenced structural, morphological and elemental electrode characteristics were further investigated for supercapacitive performance with a three electrode system in 1M KOH electrolyte. Cyclic voltammetry (CV), galvanostatic discharge (GD) and electrochemical impedance spectroscopy (EIS) tests were employed for comparative analysis of as synthesized and annealed electrodes as shown in Fig. S4 (ESI<sup>†</sup>). The as-synthesized samples showed small area CV curves excluding major noticeable redox peaks. However, the annealed samples showed improved electrochemical reactions with distinct redox peaks in large area CV curves. The A<sub>1</sub> electrode showed more significant electrochemical performance than the other samples. This comparison significantly highlights the substantial influence of the CDA mechanism in a synergetic way. The optimum capping gives the Ni rich active content of the crystalline S-NiO electrode more oxygen vacancies, improved electrical conductivity and a honeycomb like nanostructure, facilitating more active surface area/sites, accomplishing the major requirements for an efficient supercapacitor electrode with enhanced electrochemical properties as shown in Fig. 5(a). Fig. 5(b) shows the scan rate dependent performance of the optimized A<sub>1</sub> electrode. As the scan rate increases, the peak current also increases with peak shifting at higher potential, indicating good reversibility of the fast charge–discharge response. The apparent redox peaks revealed faradaic reactions occurring on the S-NiO surface (active Ni content *i.e.* Ni<sup>2+</sup> ↔ Ni<sup>3+</sup>) attributed to major capacitance contribution. The walls and surfaces of the cavities in the honeycomb like structure assist more electrolyte storage, leading to substantial charge accumulation. In this study, faradaic redox reaction involves adsorption/desorption of hydroxyl (OH<sup>−</sup>) ions at the S-NiO/electrolyte interface given by the following eqn (4).



In particular, the amount of sulfur in NiO can increase the number of electrochemically active sites, which can lead to increased interfacial dynamics by the honeycomb like structure. The specific capacitance of the electrodes was calculated from the CV curve by using equation 5:

$$C_s = \frac{A}{m \cdot v \cdot \Delta V} \quad (5)$$

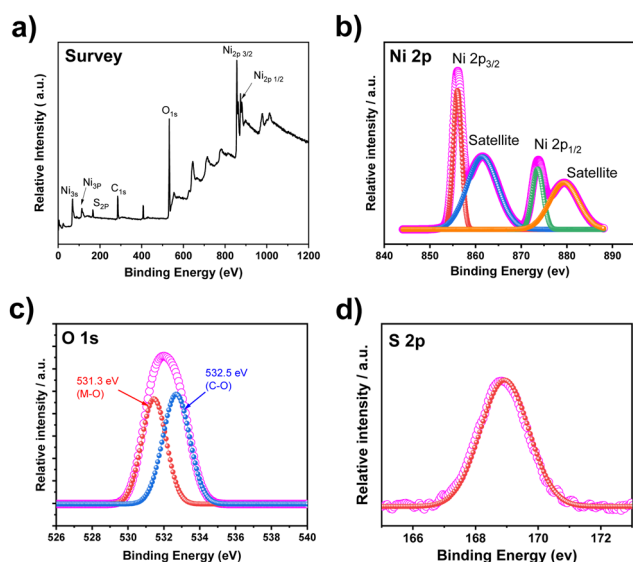


Fig. 4 (a) XPS wide survey spectrum of S-NiO, and high-resolution spectra of (b) Ni 2p, (c) O 1s and (d) S 2p.



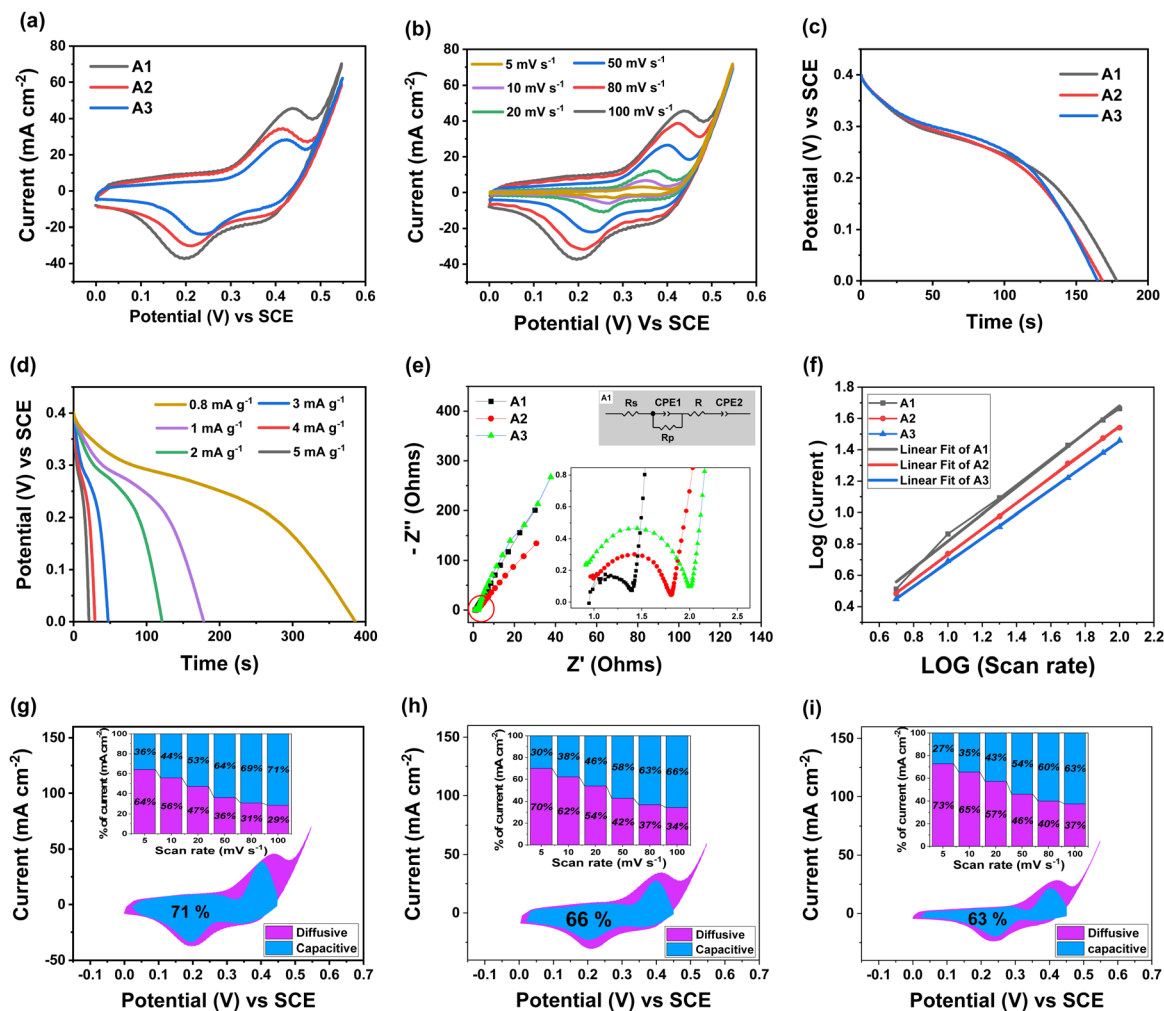


Fig. 5 (a) Comparative CV curves for electrodes A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> in aqueous 1 M KOH at a scan rate of 100 mV s<sup>-1</sup>. (b) CV curves for the optimized A<sub>1</sub> electrode at various scan rates from 2 to 100 mV s<sup>-1</sup>. (c) Comparative GD curves for electrodes A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> at 1 mA cm<sup>-2</sup>. (d) GD curves for the optimized A<sub>1</sub> electrode at various current densities of 0.8 to 5 mA cm<sup>-2</sup>. (e) Comparative EIS (Nyquist) plots for electrodes A<sub>1</sub>, A<sub>2</sub>, and A<sub>3</sub>. (f) Log of current density vs. log of scan rate plots. Comparative current contribution fractions at 100 mV s<sup>-1</sup> with inset graphs showing attribution to capacitive and diffusive charge storage for the (g) A<sub>1</sub>, (h) A<sub>2</sub> and (i) A<sub>3</sub> electrodes.

where  $A$  is the integral area under the CV curve, *i.e.*  $\int Idv$ ,  $m$  is the active mass loaded on the sample,  $\nu$  is the scan rate, and  $\Delta V$  is the operating potential window. The calculated specific capacitance values at 20 mV s<sup>-1</sup> for the A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> electrodes are 791.67 F g<sup>-1</sup>, 515.41 F g<sup>-1</sup> and 305.76 F g<sup>-1</sup>, respectively. The specific capacitance decreases with increasing capping concentration due to the slower release of Ni ions for A<sub>2</sub> and A<sub>3</sub>. Thus, less active Ni and sulfur incorporation with oxygen deficiencies was observed than for the A<sub>1</sub> electrodes. The shifting in the redox peaks with respect to increasing scan rate was mainly due to the increasing internal diffusion resistance and we remain successful at decreasing the internal diffusion resistance because of the richness in active Ni with sulfur content.<sup>66,67</sup> The annealing process has a favourable effect on redox activity as shown in Fig. S5 (ESI<sup>†</sup>).

To investigate the fast discharge ability and better stability, the galvanostatic curve was tested in 1 M KOH electrolyte for all samples as shown in Fig. S6 (ESI<sup>†</sup>). Fig. 5(c) shows the galvanostatic discharge (GD) curves of A<sub>1</sub>, A<sub>2</sub> and A<sub>3</sub> electrodes

at 1 mA cm<sup>-2</sup>. Both the GD curves for A<sub>2</sub> and A<sub>3</sub> marginally overlap due to similar kinds of morphologies along with approximately comparable incorporation of Ni active and sulfur content prepared at a high degree of complexation (Table S2, ESI<sup>†</sup>). Fig. 5(d) shows GD curves for the optimised A<sub>1</sub> electrode at various current densities ranging from 0.8 to 5 mA cm<sup>-2</sup>. The discharge time decreases with increase in current density. The A<sub>1</sub> electrode achieved a large discharge time at a lower current density value. The honeycomb like structure with appropriate Ni and S contents of the A<sub>1</sub> sample facilitates ion transfer, contributing to high and stable specific capacitance at high current densities. Thus, the A<sub>1</sub> electrode exhibited high specific capacitance, calculated by eqn (6):

$$C_s = \frac{I \times \Delta t}{m \times \Delta V} \quad (6)$$

where  $I$  is the discharge current (A),  $\Delta t$  is the discharge time (s);  $m$  is the mass of the active materials of the electrode (g), and



$\Delta V$  is the discharge potential range (V).  $C_s$  represents the calculated specific capacitance values for  $A_1$ ,  $A_2$ , and  $A_3$ , which are  $440 \text{ F g}^{-1}$ ,  $435 \text{ F g}^{-1}$ , and  $412.5 \text{ F g}^{-1}$ , respectively, at  $1 \text{ mA cm}^{-2}$ . It is observed that the specific capacitance decreases with increasing current density, which is caused by an increase in internal diffusion resistance and decrease in utilization efficiency within the active material.<sup>68</sup> The greater capacitance rate capability is mainly dependent on a fast redox reaction which can promote a low diffusion path. The electrode  $A_1$  features good electrical conductivity, ascribed to a lower band gap value (2.05 eV) than  $A_2$  (2.36 eV) and  $A_3$  (2.45 eV). Also, enriched Ni content with abundant diffusion cavities of honeycomb structures means electrolyte ions can efficiently contact the larger active surface sites of the electrode. Such cavities were not formed in the  $A_2$  and  $A_3$  electrodes. Evidently, the nonlinear GD curves confirm the pseudo-capacitive performance.

Electrochemical impedance spectroscopy (EIS) was employed for detailed investigation of all electrodes shown in Fig. S7 (ESI<sup>†</sup>). Fig. 5(e) shows Nyquist plots in a frequency range from 0.01 Hz to 10 kHz at open circuit potential (OCP), and the inset shows a magnified view along with the equivalent circuit for the  $A_1$ ,  $A_2$  and  $A_3$  electrodes. Here  $Z'$  and  $Z''$  are the real and imaginary parts of the impedance. The high and low frequency regions are associated with a semicircle and vertical sloping straight line, respectively. The  $A_1$  electrode has a vertical sloping straight line at the low frequency region and a smaller depressed arc at the high frequency region, indicating a decent capacitive storage mechanism and lower polarization resistance than the  $A_2$  and  $A_3$  electrodes. The solution resistance ( $R_s$ ), polarization resistance ( $R_p$ ) and constant phase element (CPE) of the  $A_1$ ,  $A_2$  and  $A_3$  electrodes were determined by fitting the data with the equivalent circuit and the comparative values are tabulated in Table S7 (ESI<sup>†</sup>).  $R_s$  values for the  $A_1$ ,  $A_2$  and  $A_3$  electrodes are found to be 0.93, 0.91 and 0.90  $\Omega$ , respectively, and the  $R_p$  values are 0.45, 0.97 and 1.10  $\Omega$ , respectively. It is observed that the  $R_s$  values for all samples are close and the  $A_1$  electrode showed the lowest  $R_p$  value. The interface of  $A_1$  has a honeycomb like structure, which stimulates electrochemical reaction through active surface cavities with ease for diffusion of electrolyte ions. Thus, exclusive lattice structures of  $A_1$  with great crystallinity, provided by the CDA mechanism, can be responsible for excessive reaction active sites along with appropriate doping and oxygen vacancies of the Ni rich electrode boosts electrical conductivity to promote practicable pathways for the rapid electron transfer with reduction in  $R_p$ . In summary, the CDA mechanism results in improved electrochemical performance of the S-NiO electrode as shown in Fig. S8 (ESI<sup>†</sup>) in comparison with undoped NiO.

In CV measurements, the relationship between response current ( $i$ ) and scan rate ( $\nu$ ) is crucially significant to interpret the slow diffusion-controlled process ( $i_{\text{diff}}$ ) and fast faradaic reactions on the electrode surface ( $i_{\text{cap}}$ ), given by the empirical equation

$$i(\nu) = a\nu^b \quad \text{i.e.}$$

$$i(\nu) = i_{\text{cap}} + i_{\text{diff}} = k_1\nu + k_2\nu^{1/2} \quad (7)$$

where both  $a$  and  $b$  are changeable parameters. The  $b$  value is calculated from the slope of the linear plot of  $\log i$  versus  $\log \nu$  as shown in Fig. 5 (f), providing kinetic information about the electrochemical reactions. Commonly,  $b = 1$  implies contributions from fast surface redox reactions, i.e. capacitive contribution given by  $i(\nu) = i_{\text{cap}}$  showing linear variation of peak current with scan rate. Meanwhile  $b = 0.5$  corresponds to the slow semi-infinite faradaic reactions, i.e. diffusive contribution given by  $i(\nu) = i_{\text{diff}}$ .<sup>69</sup> The  $b$  value can be useful for the sustainable design of high-performance electrode materials, (i) for distinguishing pseudocapacitive from battery-type materials, and (ii) to give more kinetic information regarding electrochemical reactions in terms of charge storage types at different scan rates.

Electrodes  $A_1$ ,  $A_2$  and  $A_3$  showed  $b$  values of 0.76, 0.71 and 0.67, respectively, calculated from Fig. 5 (f). The  $b$  values were in the range larger than 0.5 and less than 1.0. Here,  $k_1\nu$  is calculated from capacitive kinetics [ $i$  (V)  $\propto \nu$ ] and  $k_2\nu^{1/2}$  is calculated from the diffusive mechanism [ $i$  (V)  $\propto \nu^{1/2}$ ].

Fig. 5(g)–(i) show capacitive current contributions of 71%, 66% and 63%, and remaining diffusive current contributions of 29%, 34% and 37%, for the  $A_1$ ,  $A_2$  and  $A_3$  electrodes, respectively, at  $100 \text{ mV s}^{-1}$ . Thus, diffusive current contribution is observed for scan rates lower than  $20 \text{ mV s}^{-1}$ , whereas capacitive current contribution is significant for scan rates higher than  $20 \text{ mV s}^{-1}$ . These results evidently show faradaic as well as non-faradaic current contribution in the storage mechanism. Similar results of combined charge storage mechanisms have also been reported.<sup>70–72</sup> A greater capacitive contribution was observed in the  $A_1$  electrode than the  $A_2$  and  $A_3$  electrodes due to optimal structural, morphological and electrical characteristics as discussed previously.

### 3.5 Preparation of aqueous asymmetric hybrid supercapacitor (AAHSc) device

The cell setup was assembled for the aqueous asymmetric supercapacitor device by using optimized S-NiO ( $A_1$ ) as the positive electrode and graphite as the negative electrode. The graphite electrode (ash: 0.3% density:  $1.65 \text{ g cm}^{-3}$ , graininess: 0.8 mm, compressive strength: 30 MPa) was used directly without any treatment, to reduce the fabrication cost of the device as compared to other carbonous materials. Then, 1 M KOH was used to make the aqueous electrolyte. Finally, the device was tested using cyclic stability and evaluated with the energy density and power density varied in a potential window up to 1.8 V.

To test practical applications, an AAHSc was assembled as shown in Fig. 6(a1) and (a2). The charge balance ( $q_+ = q_-$ ) between the positive electrode and the negative electrode was calculated using the mass ratio from eqn 8:

$$\frac{m_+}{m_-} = \frac{C_- \times \Delta V_-}{C_+ \times \Delta V_+} \quad (8)$$

where  $m$  signifies the mass,  $C$  is the specific capacitance, and  $\Delta V$  is the potential window of the electrode. According to the mass balance, the mass ratio of the positive electrode to the negative electrode is close to 1:2.18. Furthermore, the



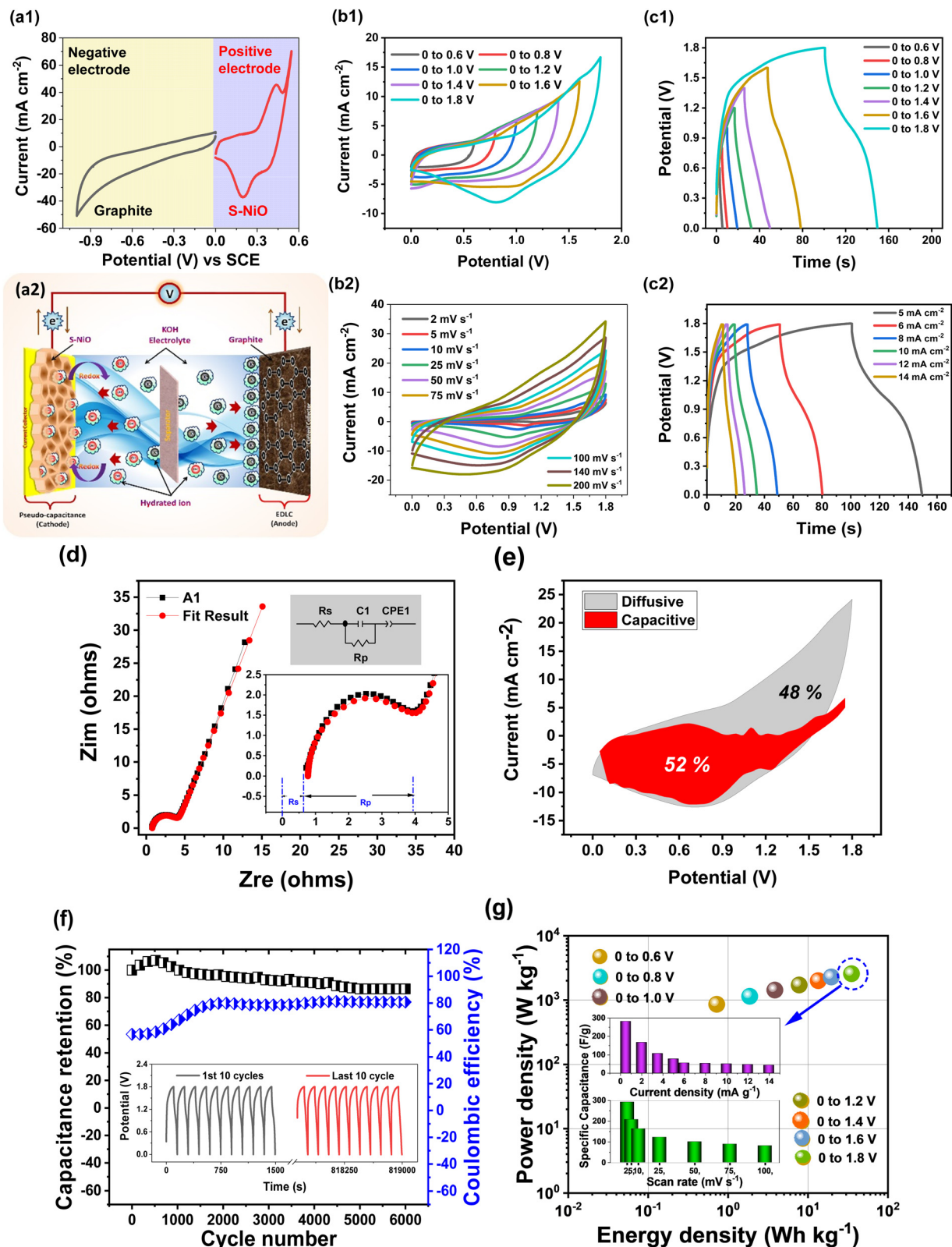


Fig. 6 a1) CV testing of individual graphite and S-NiO ( $A_1$ ) electrodes, (a2) schematic of AAHSc (S-NiO//KOH//graphite) device, (b1) CVs of operating potential window variation from 0.6 to 1.8 V at  $50 \text{ mV s}^{-1}$ , (b2) scan rate variation from 2 to 200  $\text{mV s}^{-1}$  for optimized 1.8 V window, (c1) GCDs of operating potential window variation from 0.6 to 1.8 V at  $5 \text{ mA cm}^{-2}$ , (c2) current density variation from 5 to 14  $\text{mA cm}^{-2}$  for optimized 1.8 V window, (d) EIS (Nyquist) plot of device matched with fit result for suitable circuit. (e) Capacitive and diffusive current contribution at  $100 \text{ mV s}^{-1}$ . (f) Cyclic stability and coulombic efficiency over 6000 cycles. (g) Ragone plot of device over various potential windows. The inset shows a bar diagram of the calculated specific capacitance using scan rate and current density.



electrochemical properties of the individual  $A_1$  and graphite electrodes with a three electrode cell set up were studied *via* CV at  $100 \text{ mV s}^{-1}$ , as shown in Fig. 6(a1).

Herein, the  $A_1$  electrode is operated from 0 to 0.55 V, while the graphite electrode is operated from 0 to  $-1 \text{ V}$ . Accordingly, AAHSc could afford to attain a high voltage window of 1.8 V due to the hybrid approach. The schematic illustration of the assembled  $A_1$ //KOH//graphite (AAHSc) device is shown in Fig. 6(a2) and 6(b1) reveals CV plots measured for different potential windows (0 to 0.6 V to 0 to 1.8 V) at  $50 \text{ mV s}^{-1}$  scan rate. At voltage windows up to 0.8 V, the approximately rectangular CV shape corresponds to EDLC behaviour. Furthermore, the redox peak started to appear in the CV curves as the voltage window increased up to 1.2 V, reflecting pseudocapacitive characteristics due to the faradaic redox mechanism of the  $A_1$  electrode. As the potential window increased from 0.6 V to 1.8 V, the specific capacitance increased significantly at the  $50 \text{ mV s}^{-1}$  scan rate from 33.15 to  $99.80 \text{ F g}^{-1}$ .

Fig. 6(b2) shows that the CV shape is well-maintained even at a high scan rate of  $200 \text{ mV s}^{-1}$ , which suggests the fast current response activity of the electrodes. CV curves of an AAHSc device prominently depicted a large current response at a higher scan rate without oxygen and hydrogen evolution, which confirmed an efficient charge storage behaviour. The specific capacitance of an AAHSc device delivered  $99.80 \text{ F g}^{-1}$  at  $50 \text{ mV s}^{-1}$  and the value is retained up to  $80.36 \text{ F g}^{-1}$  at  $100 \text{ mV s}^{-1}$ , indicating great capacitance rate performance. The specific capacitance values concerning the variation of the potential window, scan rate and current density are tabulated in Table S4 (ESI $^\dagger$ ).

As shown in Fig. 6(c1), GCD curves of the AAHSc device were tested at various potential windows up to 1.8 V at a constant  $5 \text{ mA cm}^{-2}$  current density. As the potential window increases from 0.6 V to 1.8 V, the specific capacitance increases significantly from 14.40 to  $77.69 \text{ F g}^{-1}$ , as obtained from equation 6. Fig. 6(c2) illustrates GCD tests conducted at various current densities ranging from 5 to  $14 \text{ mA cm}^{-2}$ . The symmetrical charge and discharge curves deliver great capacitive performance. Based on GCD evaluation, the AAHSc device delivers a specific capacitance of  $77.69 \text{ F g}^{-1}$  at  $5 \text{ mA cm}^{-2}$  and maintains  $43.03 \text{ F g}^{-1}$  at  $14 \text{ mA cm}^{-2}$ . This signifies excellent capacitance rate performance. The hybrid approach of the device achieves the operation at the higher potential window with a superior specific capacitance value.

Fig. 6(d) shows a Nyquist plot in the frequency range of 10 kHz to 0.01 Hz. The inset shows the equivalent circuit diagram to fit the results, and a magnified image at the lower frequency region. In the high frequency region, the intercept of the semicircles with the  $x$ -axis corresponds to the solution resistance ( $R_s$ ) of electrolyte and the diameter of the semicircle corresponds to the polarisation resistance ( $R_p$ ). The well fitted circuit revealed low values of  $R_s = 0.77 \Omega$  and  $R_p = 3.11 \Omega$ . The slope in the lower frequency region seems to be less, *i.e.* the diffusive resistance of the electrolyte in the AAHSc device seems to be smaller. Fig. 6(e) shows capacitive and diffusive current contributions of 52% and 48%, respectively, for the AAHSc

device, at a higher scan rate of  $100 \text{ mV s}^{-1}$ . These studies evidently suggested that a hybrid based combined charge storage mechanism, *i.e.* faradaic and non-faradaic current contribution, is reflected in the AAHSc device.

Fig. 6(f) reveals that the cyclic stability of the AAHSc device at  $5 \text{ mA g}^{-1}$  current density, for 6000 charging–discharging cycles, retained 91% of the initial capacitance. The coulombic efficiency was 80% after the 6000 cycles in aqueous 1 M KOH. The capacitance retention indicates a modest decline from  $77.69$  to  $70.07 \text{ F g}^{-1}$  after 6000 cycles, suggesting asymmetric hybrid supercapacitors deliver higher energy and power densities than EDLCs without sacrificing cycling rate capability.

Fig. 6(g) shows the correspondence between calculated energy densities ( $E$ ) and power densities ( $P$ ) of the AAHSc device with respect to potential window variation using eqn (9) and (10), respectively.<sup>73</sup> The inset image in Fig. 6(g) shows a bar diagram of the calculated specific capacitance w.r.t. scan rates and energy densities.

$$E = \frac{1}{2}CV^2 \quad (9)$$

$$P = \frac{E}{\Delta t} \quad (10)$$

where  $C$  is the specific capacitance,  $V$  is the total applied potential window and  $\Delta t$  is the discharge time, using the energy density and power density values from Table 1.

Fig. 7 shows a Ragone plot including a comparison with other reported work. Benefiting from the honeycomb like pseudo-based S-NiO electrode and EDLC based graphite as a negative electrode, AAHSc exhibits a higher energy density of  $34.96 \text{ W h kg}^{-1}$  at a power density of  $2.5 \text{ kW kg}^{-1}$  and remains at an energy density of  $19.36 \text{ W h kg}^{-1}$  at a power density of  $7.18 \text{ kW kg}^{-1}$ . These values are comparable with or even higher than those from previously reported literature summarized in Table 1.<sup>74–91</sup>

It is observed that NiO based EDLC could achieve a high power density and NiO based pseudocapacitors could achieve a high energy density. Moreover, considerable improvement in energy density is achieved while retaining a high power density for the (S-NiO//KOH//graphite) AAHSc device. This work is placed at the top right corner of the Ragone plot as shown in Fig. 7. The detailed energy and power density values of the AAHSc device compared with those in EDLC and pseudocapacitor based reported literature are shown in Table 1. In summary, the cost-effective CDA mechanism reinforced a feasible approach of using S-NiO as a potential candidate owing to excellent electrochemical performance in an aqueous asymmetric hybrid supercapacitor device.

In summary, the chemically synthesized sulfur doped NiO electrodes produced *via* the CDA mechanism played a crucial role in growth as well as structural, morphological, and compositional aspects of the electrode materials, with superior impact on electrochemical performance and long-term stability. The crystallinity improvement was attributed to annealing, with surface morphology changes that are beneficial to the





**Table 1** Comparison of the electrochemical performance of the S-NiO//KOH//graphite AAHSc device (this work) with other EDLC and pseudo based supercapacitor devices

S. no.	Material	Electrolyte	Device capacitance	Energy density	Power density	Stability	Ref.
1	N-Doped carbon from NiO arrays/Ni foam	2 M KOH	88.8 F g <sup>-1</sup> at 0.4 A g <sup>-1</sup>	27.75 W h kg <sup>-1</sup>	300 W kg <sup>-1</sup>	84.2% after 10 000 cycles	74
2	Graphite-CNT @NiO/graphene-CNT	2 M KOH	—	11.9–23.4 W h kg <sup>-1</sup>	1060–7140 W kg <sup>-1</sup>	80% after 30 000 cycles	75
3	NiO/C-HS//AC NiO-HS//AC	2 M KOH	NiO/C-HS//AC = 99 F g <sup>-1</sup> , NiO-HS//AC = 32 F g <sup>-1</sup> , both at 0.25 A g <sup>-1</sup>	NiO/C-HS//AC = 30.5 W h kg <sup>-1</sup> , NiO-HS//AC = 10.2 W h kg <sup>-1</sup>	NiO/C-HS//AC = 193 W kg <sup>-1</sup> , NiO-HS//AC = 182 W kg <sup>-1</sup>	83% after 5000 cycles	76
4	NiO/copper sheets	2 M KOH	—	8.78 W h kg <sup>-1</sup>	2500 W kg <sup>-1</sup>	131% after 5000 cycles	77
5	Ni-NiO micro flower  carbon cloth	1 M KOH	—	15.9 W h kg <sup>-1</sup>	120 W kg <sup>-1</sup>	80% after 10 000 cycles	78
6	Carboxyl groups (CPS) @ Ni  CPS core	2 M KOH	—	19.44 W h kg <sup>-1</sup>	2460 W kg <sup>-1</sup>	100% after 1000 cycles	79
7	NiO/Ni <sub>3</sub> S <sub>2</sub> //AC	3 M KOH	—	52.9 W h kg <sup>-1</sup> at 1600 W kg <sup>-1</sup>	26.3 W h kg <sup>-1</sup> at 6400 W kg <sup>-1</sup>	92.9% over 5 000 cycles	80
8	NC/Ni@NiO//AC	6 M KOH	71.4 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	19.4 W h kg <sup>-1</sup>	700 W kg <sup>-1</sup>	73.8% after 3000 cycles	81
9	MnO <sub>2</sub> /NiO@Ni//rGO	1 M KOH	215 F g <sup>-1</sup>	59.5 W h kg <sup>-1</sup>	2530 W kg <sup>-1</sup>	75% after 10000 cycles	82
10	NiO/Ni(OH) <sub>2</sub> //AC	KOH/PVA	—	28.5 W h kg <sup>-1</sup>	450 W kg <sup>-1</sup>	86.8% after 5000 cycles	83
11	NiMoO <sub>4</sub> /NiO//AC	3 M KOH	—	38 W h kg <sup>-1</sup>	96 W kg <sup>-1</sup>	95.5% after 5000 cycles	84
12	NiCo <sub>2</sub> O <sub>4</sub> /NiO/Co <sub>3</sub> O <sub>4</sub> //AC	—	121 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	43.02 W h kg <sup>-1</sup>	820.29 W kg <sup>-1</sup>	83% after 2000 cycles	85
13	NiO@NFC//NiO@NFC	Li-gel	161 F g <sup>-1</sup> at 1.0 A g <sup>-1</sup>	22 W h kg <sup>-1</sup>	491.9 W kg <sup>-1</sup>	96.0% after 5000 cycles	86
14	NiO@ITO//NiO@ITO	Li-gel	85 F g <sup>-1</sup> at 1.0 A g <sup>-1</sup>	11.8 W h kg <sup>-1</sup>	500 W kg <sup>-1</sup>	92.2% after 5000 cycles	86
15	ZnO/NiO//ZnO/NiO	—	—	26.73 W h kg <sup>-1</sup>	641.5 W kg <sup>-1</sup>	73.43% after 5000 cycles	87
16	PNFA//PNFA Porous NiO nanoflake array (PNFA)	2 M KOH	—	39.3 W h kg <sup>-1</sup>	550 W kg <sup>-1</sup>	92.4% after 5000 cycles	88
17	NiO//NiO	6 M KOH	307 F g <sup>-1</sup> at 0.5 A g <sup>-1</sup>	10.53 W h kg <sup>-1</sup>	124.31 W kg <sup>-1</sup>	96% after 3000 cycles	89
18	NiO//α-Fe <sub>2</sub> O <sub>3</sub>	PVA/KOH	—	12.4 W h kg <sup>-1</sup>	951 W kg <sup>-1</sup>	85% after 10000 cycles	90
19	NiCo <sub>2</sub> O <sub>4</sub> /NiO//Fe <sub>2</sub> O <sub>3</sub>	1 M KOH	79 F g <sup>-1</sup> at 1 mA cm <sup>-2</sup>	19 W h kg <sup>-1</sup>	157 W kg <sup>-1</sup>	97% after 5000 cycles	91
20	S-NiO//graphite (AAHSc)	1 M KOH	77.69 F g <sup>-1</sup> at 5 mA cm <sup>-2</sup>	34.96 W h kg <sup>-1</sup> at 2567 W kg <sup>-1</sup>	19.36 W h kg <sup>-1</sup> at 7180 W kg <sup>-1</sup>	91% after 6000 cycles	This work

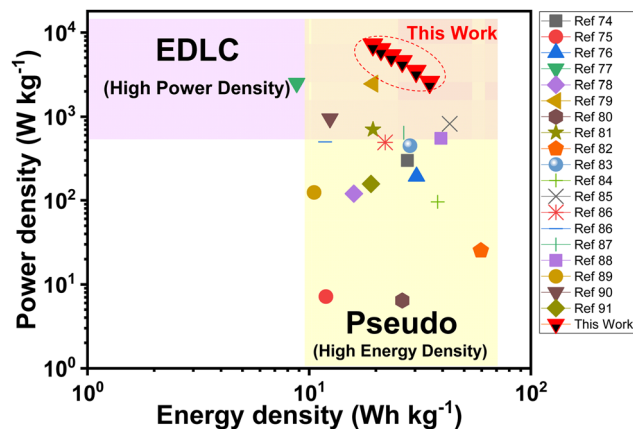


Fig. 7 Ragone plot of the S-NiO//KOH//graphite AAHSc device (this work) with improved energy density values compared with other EDLC and pseudo based supercapacitor devices.

electrochemical performance of the sulfur doped NiO structure accompanied by the lowest dislocation density and microstrain. This facilitates favourable conditions for fast charge discharge progression pathways for the rapid transfer of electrons originating from sulfur doping. The Ni rich and high oxygen vacancies of the crystalline S-NiO served as active resources and resulted in improved electrical conductivity. Faradaic redox reactions involve adsorption-desorption of hydroxyl ions at the surface of the honeycomb like structured S-NiO. More active surface sites resulting in more electrolyte access with extra charge accumulation are made possible by cavities in the honeycomb-like structure. This satisfies key requirements for an effective supercapacitor electrode and supports improved electrochemical properties. Thus, the synergistic characteristics of the sulfur doped NiO structure facilitates the AAHSc device with ease, and is feasible for energy storage applications.

## Conclusions

In conclusion, a sulfur doped nickel oxide material on a stainless-steel substrate is effectively prepared *via* a successful chemical bath method. The CDA mechanism assists the structural-morphological evolution and offers improved electrochemical functioning of the S-NiO electrode for the AAHSc device. The structural evolution of the S-NiO was observed from amorphous to crystalline, and was influenced by the CDA mechanism. Increasing the capping rate affected the elemental composition by decreasing the active Ni and S content in the sample. A cavity surface of an S-NiO honeycomb nanostructure exhibited notable specific capacitance values of 791.67 F g<sup>-1</sup> and 766 F g<sup>-1</sup> at a 20 mV s<sup>-1</sup> scan rate and 0.8 mA cm<sup>-2</sup> current density, respectively. The AAHSc fabricated by assembly with pseudocapacitive S-NiO as the positive electrode and EDLC-type graphite as the negative electrode synergistically achieved a higher cell voltage up to 1.8 V and a maximum specific capacitance of 77.69 F g<sup>-1</sup> at 5 mA cm<sup>-2</sup>. Surface reactivity improvement was caused by morphology modification and rich

Ni<sup>2+</sup> sites along with sulfur doping, *i.e.* oxygen deficiency of the electrode. This would lead to fast and efficient charge storage to boost the supercapacitive performance of the S-NiO//KOH//graphite AAHSc device with a high energy density of 34.96 W h kg<sup>-1</sup> and high power density of 7.18 kW kg<sup>-1</sup>. The high rate capability of 91% capacity retention results in 81% coulombic efficiency being sustained after 6,000 cycles. These results demonstrate an aqueous asymmetric hybrid approach toward cost effective and high-performance electrodes for energy storage applications.

## Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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